International **ISPR** Rectifier

SCHOTTKY RECTIFIER

30BQ015PbF

3 Amp

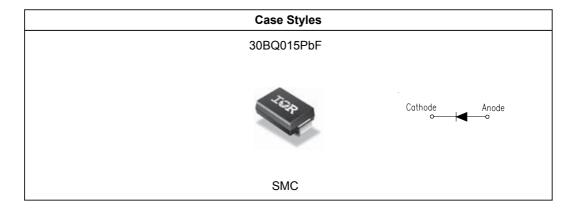
Characteristics	Value	Units
I _{F(AV)} Rectangular waveform	3.0	A
V _{RRM}	15	V
$I_{FSM} @t_p=5\mu s sine$	650	А
V _F @1.0Apk, T _J =75°C	0.30	V
T _J range	- 55 to 125	°C

Major Ratings and Characteristics

Description/Features

The 30BQ015PbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. The proprietary barrier technology allows for reliable operation up to 125°C junction temperature. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery

- charging, and reverse battery protection. 125°C T₁ operation (V_R < 5V)
- Optimized for OR-ing applications
- Ultra low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Lead-Free ("PbF" suffix)



30BQ015PbF

Bulletin PD-20406 rev. A 05/05

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Voltage Ratings

Part number	30BQ015PbF	
V _R Max. DC Reverse Voltage (V)	15	
V _{RWM} Max. Working Peak Reverse Voltage (V)	25	

Absolute Maximum Ratings

	Parameters	30BQ	Units	Conditions	
I _{F(AV)}	Max. Average Forward Current	3.0	А	50% duty cycle @ T_L = 83 °C, rectangular wave form	
		4.0		50% duty cycle @ T _L = 78 °C, re	ectangular wave form
I _{FSM}	Max. Peak One Cycle Non-Repetitive	650	А	5µs Sine or 3µs Rect. pulse	Following any rated load condition and
	Surge Current	75		10ms Sine or 6ms Rect. pulse	with rated V _{RRM} applied
E _{AS}	Non Repetitive Avalanche Energy	1.5	mJ	$T_J = 25 ^{\circ}C, I_{AS} = 0.5A, L = 12mH$	
I _{AR}	Repetitive Avalanche Current	0.5	A	Current decaying linearly to zer Frequency limited by T _J max. V	

Electrical Specifications

	Parameters	30BQ	Units	Conditions	
V _{FM}	Max. Forward Voltage Drop (1)	0.35	V	@ 3A	T _J = 25 °C
		0.40	V	@ 6A	
		0.30	V	@ 3A	T _J = 75 °C
		0.35	V	@ 6A	
I _{RM}	Max. Reverse Leakage Current (1)	4	mA	T _J = 25 °C	V_R = rated V_R
		50	mA	T _J = 100 °C	
CT	Max. Junction Capacitance	1120	pF	$V_R = 5V_{DC}$ (test signal range 100KHz to 1Mhz) 25°C	
Ls	Typical Series Inductance	3.0	nH	Measured lea	ad to lead 5mm from package body
dv/dt	Max. Voltage Rate of Change	10000	V/µs	(Rated V _R)	

(1) Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters	30BQ	Units	Conditions
TJ	Max. Junction Temperature Range (*)	- 55 to 125	°C	
T _{stg}	Max. Storage Temperature Range	- 55 to 150	°C	
R _{thJL}	Max. Thermal Resistance Junction to Lead (**)	12	°C/W	DC operation
R _{thJA}	Max. Thermal Resistance Junction to Ambient	46	°C/W	DC operation
wt	Approximate Weight	0.24 (0.008)	g(oz.)	
	Case Style	SMC		Similar to DO-214AB
	Device Marking	IR3C		

 $\binom{*}{dTj} \frac{dPtot}{dTj} < \frac{1}{Rth(j-a)} thermal \ runaway \ condition \ for \ a \ diode \ on \ its \ own \ heatsink$ (**) Mounted 1 inch square PCB

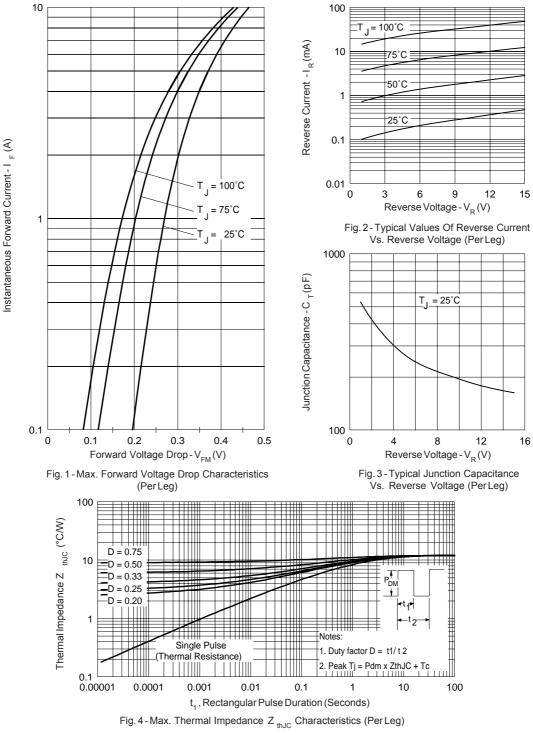
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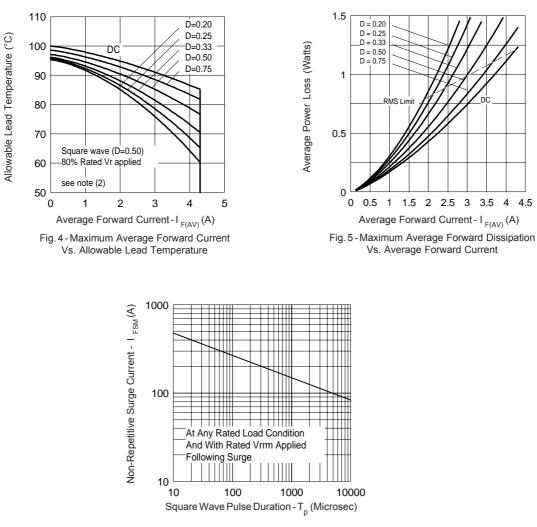


Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

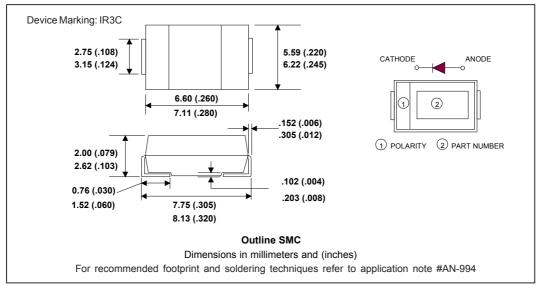
(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward Power Loss = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6); $Pd_{REV} = Inverse Power Loss = V_{R1} \times I_R (1-D); I_R @ V_{R1} = 80\% rated V_R$

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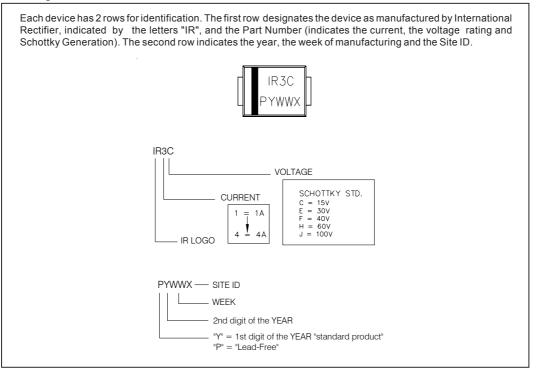
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Outline Table



Marking & Identification

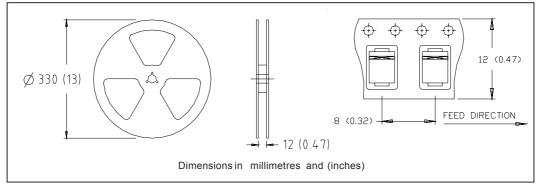


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Tape & Reel Information



Ordering Information Table

Device Code	30 B Q 015 TR PbF
	1 - Current Rating
	 B = Single Lead Diode Q = Schottky Q Series
	- Voltage Rating (015 = 15V)
	- • none = Box (1000 pieces)
	 TR = Tape & Reel (3000 pieces) onone = Standard Production
	• PbF = Lead-Free

Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level and Lead-Free. Qualification Standards can be found on IR's Web site.



IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105 TAC Fax: (310) 252-7309 05/05

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